MBR1635 THRU MBR1660

SCHOTTKY BARRIER RECTIFIER Reverse Voltage - 35 to 60 V Forward Current - 16 A

Features

- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- High current capability
- · Low power loss, high efficiency
- Low forward voltage drop
- For use in low voltage, high frequency inverters, free whelling, and polarity protection applications

Mechanical Data

- Case: Molded plastic, TO-220A
- Epoxy: UL 94V-0 rate flame retardant
- Terminals: Leads solderable per MIL-STD-202 Method 208 guaranteed
- Polarity: As marked
- Mounting position: Any

$\begin{array}{c} \hline \textbf{TO-220A} \\ \hline & 187 (4.7) \\ \hline & 148 (3.8) \\ \hline & 148 (3.7) \\ \hline & 148 (3.7) \\ \hline & 146 (3.7) \\ \hline & 146 (3.7) \\ \hline & 146 (3.7) \\ \hline & 100 \\ \hline$

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	MBR1635	MBR1645	MBR1650	MBR1660	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	V
Maximum RMS Voltage	V _{RMS}	24	31	35	42	V
Maximum DC Blocking Voltage	V _{DC}	35	45	50	60	V
Maximum Average Forward Rectified Current T_{c} = 125 °C	I _{F(AV)}	16			А	
Peak Repetitive Forward Current at T _C = 125 °C (Rated V _R , Sq. Wave, 20 KHz)	I _{FRM}	32			А	
Peak Forward Surge Current, 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	150			А	
Peak Repetitive Reverse Current at tp = 2 µs, 1 KHz	I _{RRM}	1 0.5		.5	Α	
Maximum Forward Voltage ¹⁾ at $I_F = 16 \text{ A}$, $T_C = 25 \text{ °C}$ at $I_F = 16 \text{ A}$, $T_C = 125 \text{ °C}$	V _F	0.63 0.57			75 65	V
Maximum Reverse Current at Rated DCat $T_c = 25 \text{ °C}$ Blocking Voltageat $T_c = 125 \text{ °C}$	I _R	0.2 40		1 50		mA
Voltage Rate of Change (Rated V_R)	dv/dt	10,000				V/µs
Typical Thermal Resistance	$R_{ extsf{ heta}JC}$	1.5			°C/W	
Operating Temperature Range	TJ	- 55 to + 150			°C	
Storage Temperature Range	Ts	- 55 to + 175				°C

¹⁾ Pulse test: 300 µs pulse width, 1% duty cycle















